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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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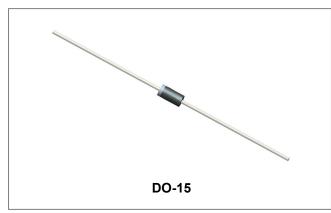








### **SB2100 SCHOTTKY RECTIFIER**



#### **Features**

- Schottky Barrier Chip
- Ideally Suited for Automatic Assembly
- Low Power Loss, High Efficiency
- Surge Overload Rating to 50A Peak
- For Use in Low Voltage Application
- Guard Ring Die Construction
- Plastic Case Material has UL Flammability
- Classification Rating 94V-O
- Green Products in Compliance with the RoHS Directive
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### **Circuit Diagram**



#### **Applications**

- · Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Disk drives

### **Maximum Ratings**

| Characteristics  | Symbol   | Condition   | Max. | Units |
|--|--|---|------|-------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage | $egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$ | -   | 100  | V     |
| Average Rectified Forward Current  | I <sub>F (AV)</sub>                                    | 50% duty cycle @T <sub>C</sub> =100°C rectangular wave form(L=0.375") | 2.0  | Α     |
| Peak One Cycle Non-Repetitive Surge Current  | I <sub>FSM</sub>                                       | 8.3 ms, half Sine pulse, T <sub>J</sub> = 25℃                         | 50   | Α     |

#### **Electrical Characteristics**

| Characteristics       | Symbol          | Condition   | Тур. | Max. | Units |
|-----------------------|-----------------|---|------|------|-------|
| Forward Voltage Drop* | $V_{F1}$        | @ 2.0A, Pulse, T <sub>J</sub> = 25℃                 | 0.70 | 0.85 | V     |
| Reverse Current*      | I <sub>R1</sub> | $@V_R = \text{rated } V_R$<br>$T_J = 25 ^{\circ} C$ | 0.02 | 0.5  | mA    |
|                       | I <sub>R2</sub> | $@V_R = \text{rated } V_R$<br>$T_J = 100^{\circ}C$  | 10   | 20   | mA    |
| Junction Capacitance  | Сл              | $@V_R = 5V, T_C = 25 °C$<br>$f_{SIG} = 1MHz$        | 120  | 140  | pF    |

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%



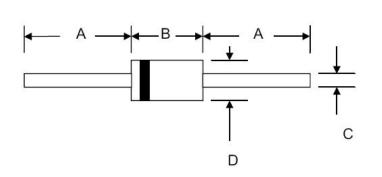




### **Thermal-Mechanical Specifications**

| Characteristics                        | Symbol            | Condition    | Specification | Units |
|--|-------------------|--------------|---------------|-------|
| Junction Temperature                   | TJ                | -            | -55 to +150   | °C    |
| Storage Temperature                    | T <sub>stg</sub>  | -            | -55 to +150   | °C    |
| Typical Thermal Resistance Junction to | R <sub>θ</sub> JC | DC operation | 8             | °C/W  |
| Case                                   |                   |              |               |       |
| Approximate Weight                     | wt                | -            | 0.093         | g     |

### **Mechanical Dimensions DO-15**



| SYMBOL | Millimeters |      | Inches |       |  |
|--------|-------------|------|--------|-------|--|
| OTMBOL | Min.        | Max. | Min.   | Max.  |  |
| Α      | 25.4        | -    | 1.000  | -     |  |
| В      | 5.5         | 7.62 | 0.217  | 0.300 |  |
| С      | 0.7         | 0.9  | 0.028  | 0.034 |  |
| D      | 2.6         | 3.6  | 0.104  | 0.140 |  |

### **Ordering Information**

| Device | Package         | Shipping      |  |
|--------|-----------------|---------------|--|
| SB2100 | DO-15 (Pb-Free) | 3000pcs /tape |  |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

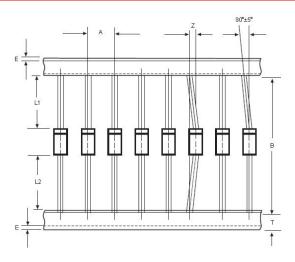
### **Marking Diagram**

Where XXXXX is YYWWL

SB = Device Type
2 = Forward Current (2A)
100 = Reverse Voltage (100V)

SSG = SSG YY = Year WW = Week L = Lot Number

## **Carrier Tape Specification DO-15**



| SYMBOL  | Millimeters |      |  |
|---------|-------------|------|--|
|         | Min.        | Max. |  |
| А       | 4.50        | 5.50 |  |
| В       | 50.9        | 53.9 |  |
| Z       | -           | 1.20 |  |
| Т       | 5.60        | 6.40 |  |
| Е       | -           | 0.80 |  |
| IL1-L2I | -           | 1.0  |  |

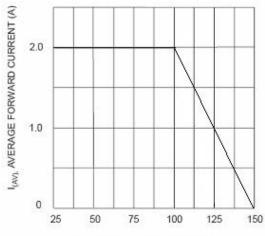
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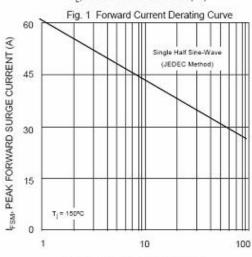




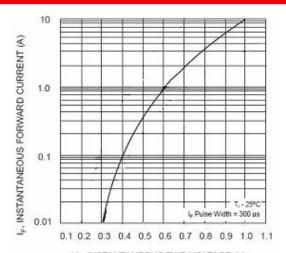
### **Ratings and Characteristics Curves**



T<sub>L</sub>, LEAD TEMPERATURE (°C)



NUMBER OF CYCLES AT 60 Hz Fig. 3 Max Non-Repetitive Peak Fwd Surge Current



V<sub>F</sub>, INSTANTANEOUS FWD VOLTAGE (V) Fig. 2 Typ. Forward Characteristics

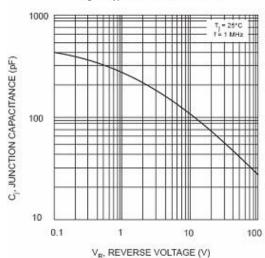
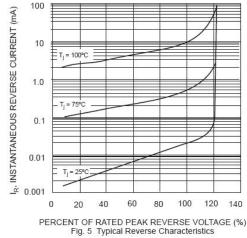


Fig. 4 Typical Junction Capacitance



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